

## CMOS Photoelectric Smoke Detector ASIC with Interconnect

### Features

- Internal Power On Reset
- Low Quiescent Current Consumption
- ESD Protection on all Pins
- Interconnect up to 40 Detectors
- Temporal Horn Pattern
- Low Battery and Chamber Test
- Compatible with Motorola, Inc. MC145012DWR2
- UL<sup>®</sup>-Recognized per File S24036
- Packaging: 16-Lead PDIP, 16-Lead SOIC, 16-Lead SOIC (Wide)

### General Description

The RE46C141 is a low-power CMOS photoelectric-type smoke detector IC. With minimal external components this circuit will provide all the required features for a photoelectric-type smoke detector.

The design incorporates a gain-selectable photo amplifier for use with an infrared emitter/detector pair.

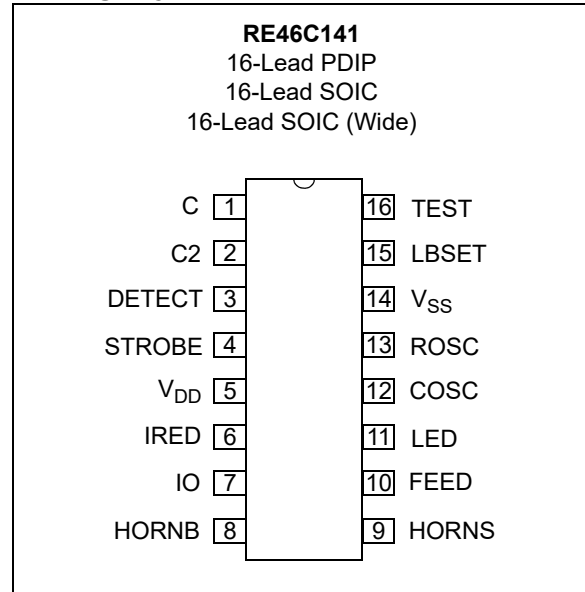
An internal oscillator strobes power to the smoke detection circuitry for 100  $\mu$ s every 8.1s to keep standby current to a minimum. If smoke is sensed the detection rate is increased to verify an alarm condition. A High Gain mode is available for push button chamber testing.

A check for a low battery condition and chamber integrity is performed every 32s while in standby. The temporal horn pattern supports the NFPA 72<sup>®</sup> (National Fire Alarm and Signaling Code<sup>®</sup>) emergency evacuation signal.

An interconnect pin allows multiple detectors to be connected such that when one units alarms, all units will sound.

The RE46C141 is recognized by UL LLC for use in smoke detectors that comply with specification UL217 and UL268.

### Package Types





## 1.0 ELECTRICAL CHARACTERISTICS

### Absolute Maximum Ratings†, ‡

Supply Voltage ( $V_{DD}$ ) .....	+12.5V
Input Voltage Range Except FEED, IO ( $V_{IN}$ ) .....	-0.3V to $V_{DD}$ +0.3V
FEED Input Voltage Range ( $V_{INFD}$ ) .....	-10V to +22V
IO Input Voltage Range ( $V_{IO1}$ ) .....	-0.3V to +17V
Input Current except FEED ( $I_{IN}$ ) .....	±10 mA
Operating Temperature ( $T_A$ ) .....	-25°C to +75°C
Storage Temperature ( $T_{STG}$ ) .....	-55°C to +125°C
Maximum Junction Temperature ( $T_J$ ) .....	+150°C

† **Notice:** Stresses above those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions, above those indicated in the operational listings of this specification, is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

‡ **Notice:** This product utilizes CMOS technology with static protection; however proper ESD prevention procedures should be used when handling this product. Damage can occur when exposed to extremely high static electrical charge.

# RE46C141

## DC ELECTRICAL CHARACTERISTICS

<b>Electrical Specifications:</b> Unless otherwise indicated, all parameters apply at Typical Application, $T_A = -25^{\circ}\text{C}$ to $+75^{\circ}\text{C}$ , $V_{DD} = 9\text{V}$							
Parameter	Sym.	Test Pin	Min.	Typ.	Max.	Units	Conditions
Supply Voltage	$V_{DD}$	5	6	—	12	V	Operating
Supply Current	$I_{DD1}$	5	—	4	6	$\mu\text{A}$	Configured as in <a href="#">Figure Typical Applications</a> , $\text{COSC} = V_{SS}$
	$I_{DD2}$	5	—	5.5	8	$\mu\text{A}$	Configured as in <a href="#">Figure Typical Applications</a> , $V_{DD} = 12\text{V}$ , $\text{COSC} = V_{SS}$
	$I_{DD3}$	5	—	—	2	$\text{mA}$	Configured as in <a href="#">Figure Typical Applications</a> , STROBE on, IRED off, $V_{DD} = 12\text{V}$
	$I_{DD4}$	5	—	—	3	$\text{mA}$	Configured as in <a href="#">Figure Typical Applications</a> , STROBE on, IRED on, $V_{DD} = 12\text{V}$ , <a href="#">Note 1</a>
Input Voltage High	$V_{IH1}$	10	6.2	4.5	—	V	FEED
	$V_{IH2}$	7	3.2	—	—	V	No Local Alarm, IO as an Input
	$V_{IH4}$	16	8.5	—	—	V	TEST
Input Voltage Low	$V_{IL1}$	10	—	4.5	2.7	V	FEED
	$V_{IL2}$	7	—	—	1.5	V	No Local Alarm, IO as an Input
	$V_{IL4}$	16	—	—	7	V	TEST
Input Leakage Low	$I_{IL1}$	1,2,3	—	—	-100	$\text{nA}$	$V_{DD} = 12\text{V}$ , $\text{COSC} = 12\text{V}$ , STROBE active
	$I_{IL2}$	12,15	—	—	-100	$\text{nA}$	$V_{DD} = 12\text{V}$ , $V_{IN} = V_{SS}$
	$I_{IL3}$	16	—	—	-1	$\mu\text{A}$	$V_{DD} = 12\text{V}$ , $V_{IN} = V_{SS}$
	$I_{LFD}$	10	—	—	-50	$\mu\text{A}$	FEED = -10V
Input Leakage High	$I_{IH1}$	1,2	—	—	100	$\text{nA}$	$V_{DD} = 12\text{V}$ , $V_{IN} = V_{DD}$ , STROBE active
	$I_{IH2}$	3,12,15	—	—	100	$\text{nA}$	$V_{DD} = 12\text{V}$ , $V_{IN} = V_{DD}$
	$I_{HFD}$	10	—	—	50	$\mu\text{A}$	FEED = 22V
Input Pull Down Current	$I_{PD1}$	16	0.25	—	10	$\mu\text{A}$	$V_{IN} = V_{DD}$
	$I_{PDIO1}$	7	20	—	80	$\mu\text{A}$	$V_{IN} = V_{DD}$
	$I_{PDIO2}$	7	—	—	140	$\mu\text{A}$	$V_{IN} = 17\text{V}$ , $V_{DD} = 12\text{V}$
Output Leakage Current Low	$I_{OZL1}$	11,13	—	—	-1	$\mu\text{A}$	Output OFF, Output = $V_{SS}$
Output Leakage Current High	$I_{OZH1}$	11,13	—	—	1	$\mu\text{A}$	Output OFF, Output = $V_{DD}$

**Note 1:** Does not include Q3 emitter current.

**2:** Not production tested.

**3:** Typical values are for design information and are not guaranteed. Limits over the specified temperature range are not production tested and are based on characterization data.

## DC ELECTRICAL CHARACTERISTICS (CONTINUED)

**Electrical Specifications:** Unless otherwise indicated, all parameters apply at Typical Application,  $T_A = -25^{\circ}\text{C}$  to  $+75^{\circ}\text{C}$ ,  $V_{DD} = 9\text{V}$

Parameter	Sym.	Test Pin	Min.	Typ.	Max.	Units	Conditions
Output Voltage Low	$V_{OL1}$	8,9	—	—	1	V	$I_{OL} = 16\text{ mA}$ , $V_{DD} = 6.5\text{V}$
	$V_{OL2}$	13	—	0.5	—	V	$I_{OL} = 5\text{ mA}$ , $V_{DD} = 6.5\text{V}$
	$V_{OL3}$	11	—	—	0.6	V	$I_{OL} = 10\text{ mA}$ , $V_{DD} = 6.5\text{V}$
Output Voltage High	$V_{OH1}$	8,9	5.5	—	—	V	$I_{OH} = -16\text{ mA}$ , $V_{DD} = 6.5\text{V}$
Output Current	$I_{IOH1}$	7	-4	—	-16	mA	Alarm, $V_{IO} = V_{DD} - 2\text{V}$ or $V_{IO} = 0\text{V}$
	$I_{IODMP}$	7	5	—	—	mA	At Conclusion of Local Alarm or Test, $V_{IO} = 1\text{V}$
Low Battery Alarm Voltage	$V_{LB}$	5	6.9	7.2	7.5	V	$R_{14} = 100\text{ k}\Omega$ , $R_{15} = 47\text{ k}\Omega$
Output Voltage	$V_{STOF}$	4	$V_{DD} - 0.1$	—	—	V	STROBE OFF, $V_{DD} = 12\text{V}$ , $I_{OUT} = -1\text{ }\mu\text{A}$
	$V_{STON}$	4	$V_{DD} - 5.3$	$V_{DD} - 5$	$V_{DD} - 4.7$	V	STROBE ON, $V_{DD} = 9\text{V}$ , $I_{OUT} = 100\text{ }\mu\text{A}$ to $500\text{ }\mu\text{A}$
	$V_{IREDOF}$	6	—	—	0.1	V	IRED OFF, $V_{DD} = 12\text{V}$ , $I_{OUT} = 1\text{ }\mu\text{A}$
	$V_{IREDON}$	6	2.25	3.1	3.75	V	IRED ON, $V_{DD} = 9\text{V}$ , $I_{OUT} = 0\text{ mA}$ to $-6\text{ mA}$ , $T_A = 25^{\circ}\text{C}$
Common Mode Voltage	$V_{CM1}$	1,2,3	0.5	—	$V_{DD} - 2$	V	Local smoke, Push to Test or Chamber Test, <a href="#">Note 2</a>
Smoke Comparator Reference	$V_{REF}$	-	$V_{DD} - 3.85$	—	$V_{DD} - 3.15$	V	Internal Reference
Temperature Coefficient	$TC_{ST}$	4	—	0.01	—	$\%/^{\circ}\text{C}$	$V_{DD} = 6\text{V}$ to $12\text{V}$ , STROBE Output Voltage
	$TC_{IRED}$	6	—	0.3	—	$\%/^{\circ}\text{C}$	$V_{DD} = 6\text{V}$ to $12\text{V}$ , IRED Output Voltage
Line Regulation	$\Delta V_{STON}$	4,5	—	-50	—	dB	Active, $V_{DD} = 6\text{V}$ to $12\text{V}$
Line Regulation	$\Delta V_{IREDON}$	6,5	—	-30	—	dB	Active, $V_{DD} = 6\text{V}$ to $12\text{V}$

**Note 1:** Does not include Q3 emitter current.

**2:** Not production tested.

**3:** Typical values are for design information and are not guaranteed. Limits over the specified temperature range are not production tested and are based on characterization data.

# RE46C141

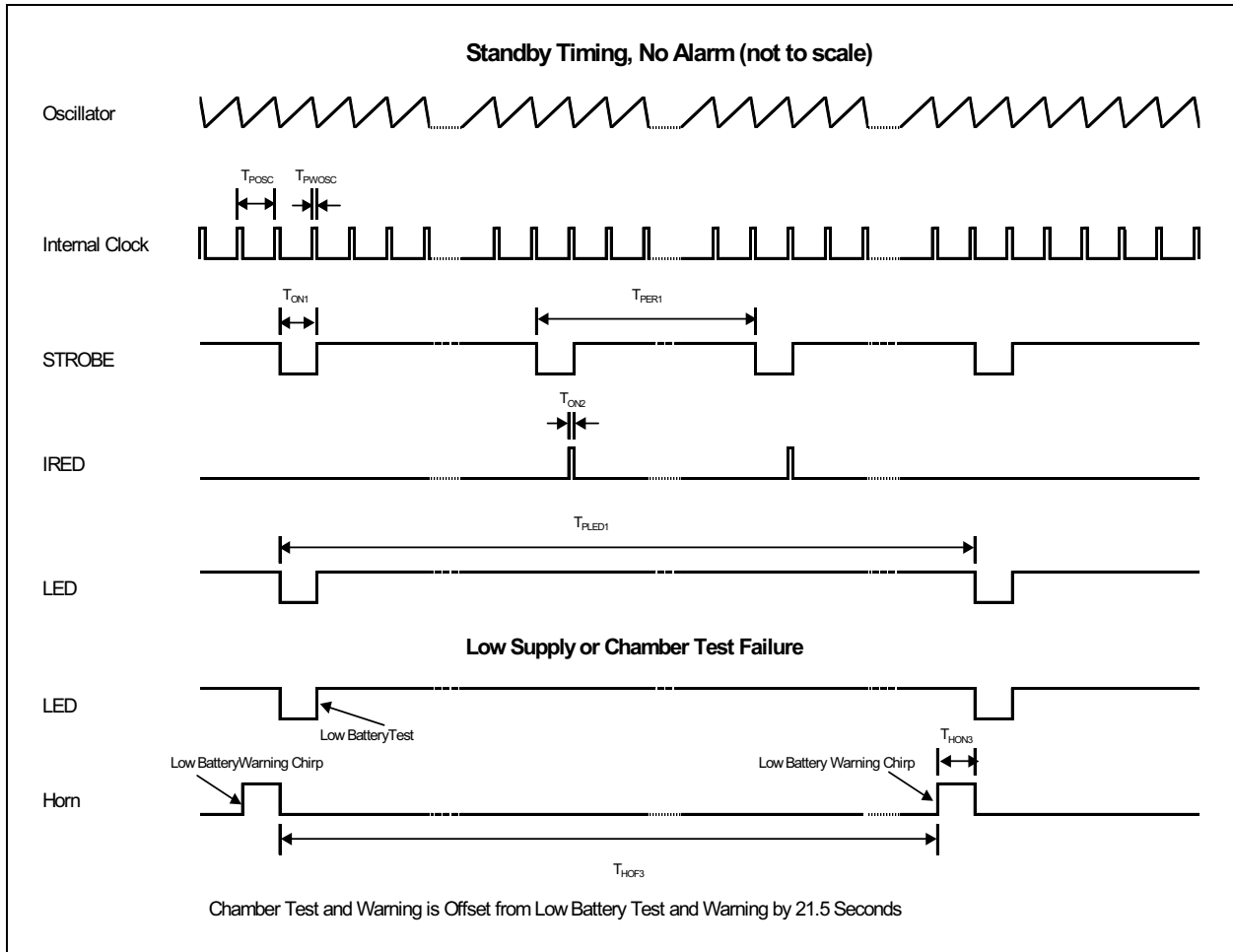
## AC ELECTRICAL CHARACTERISTICS

**Electrical Specifications:** Unless otherwise indicated, all parameters apply at  $T_A = -25^{\circ}\text{C}$  to  $75^{\circ}\text{C}$ ,  $V_{DD} = 9\text{V}$ ,  $V_{SS} = 0\text{V}$ , Component Values from [Figure Typical Applications](#);  $R9 = 100\text{ k}\Omega$ ,  $R12 = 7.5\text{ M}\Omega$ ,  $C5 = 1.5\text{ nF}$

Parameter	Sym.	Test Pin	Min.	Typ.	Max.	Units	Conditions
Oscillator Period	$T_{\text{POSC}}$	12	7.1	7.9	8.6	ms	No Alarm Condition, <a href="#">Note 2</a>
LED and STROBE On Time	$T_{\text{ON1}}$	11,4	7.1	7.9	8.6	ms	Operating
LED Period	$T_{\text{PLED1}}$	11	28.8	32.4	35.2	s	Standby, No Alarm
	$T_{\text{PLED2}}$	11	0.45	0.5	0.55	s	Local Alarm Condition
	$T_{\text{PLED4}}$	11	LED IS NOT ON			s	Remote Alarm Only
STROBE and IRED Pulse Period	$T_{\text{PER1}}$	4,6	7.3	8.1	8.8	s	Standby, No Alarm
	$T_{\text{PER1A}}$	4,6	1.8	2	2.2	s	Standby, After 1 Valid Smoke Sample
	$T_{\text{PER1B}}$	4,6	0.9	1	1.1	s	Standby, After 2 Consecutive Valid Smoke Samples
	$T_{\text{PER2}}$	4,6	0.9	1	1.1	s	In Local Alarm (3 Consecutive Valid Smoke Samples)
	$T_{\text{PER3}}$	4,6	7.3	8.1	8.8	s	In Remote Alarm
	$T_{\text{PER4}}$	4,6	—	250	—	ms	Pushbutton Test
	$T_{\text{PER5}}$	4,6	28.8	—	35.2	s	Chamber Test or Low Battery Test, No Alarms
IRED On Time	$T_{\text{ON2}}$	6	94	104	115	$\mu\text{s}$	Operating, <a href="#">Note 2</a>
Horn On Time	$T_{\text{HON1}}$	8,9	450	500	550	ms	Operating, Alarm Condition, <a href="#">Note 1</a>
	$T_{\text{HON2}}$	8,9	7.1	7.9	8.6	ms	Low Battery or Failed Chamber Test, No Alarm
Horn Off Time	$T_{\text{HOF1}}$	8,9	450	500	550	ms	Operating, Alarm Condition, <a href="#">Note 1</a>
	$T_{\text{HOF2}}$	8,9	1.35	1.5	1.65	s	Operating, Alarm Condition, <a href="#">Note 1</a>
	$T_{\text{HOF3}}$	8,9	28.8	32.4	35.2	s	Low Battery or Failed Chamber Test, No Alarm
IO Charge Dump Duration	$T_{\text{IODMP}}$	7	0.68	—	1.1	s	At Conclusion of Local Alarm or Test
IO Delay	$T_{\text{IODLY1}}$	7	—	0	—	s	From Start of Local Alarm to IO Active
IO Filter	$T_{\text{IOFILT}}$	7	—	—	450	ms	IO pulse width guaranteed to be filtered. IO as Input, No Local Alarm
Remote Alarm Delay	$T_{\text{IODLY2}}$	7	0.9	—	1.65	s	No Local Alarm, From IO Active Horn Active

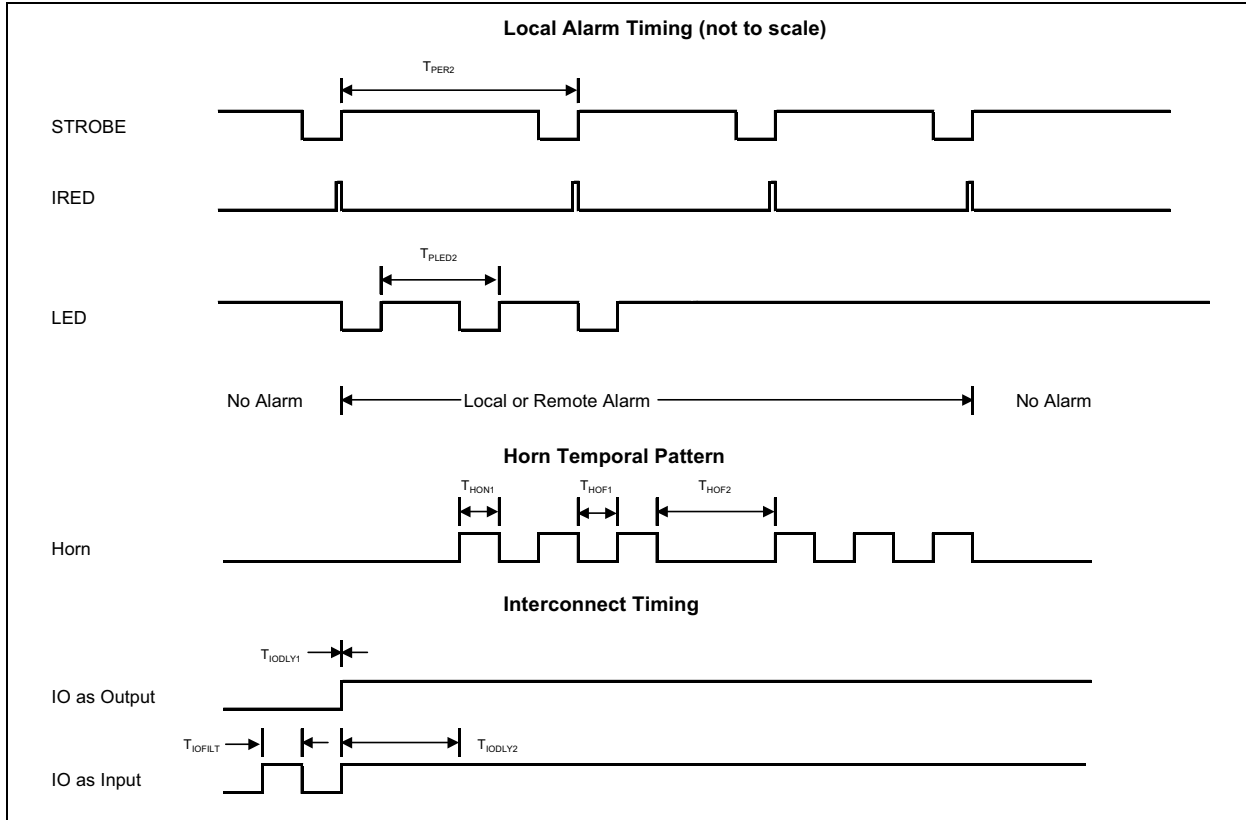
**Note 1:** See [Figure 1-1](#) and [Figure 1-2](#) for Horn Temporal Pattern.

**Note 2:**  $T_{\text{POSC}}$  and  $T_{\text{ON2}}$  are 100% production tested. All other timing is guaranteed by functional testing.



**FIGURE 1-1:** Standby Timing Diagram.

# RE46C141



**FIGURE 1-2:** Local Alarm Timing Diagram.

- Note 1:** Smoke is not sampled when the horn is active. Horn cycle is self-completing in local alarm, but not in remote alarm.
- 2:** Low battery warning chirp is suppressed in local or remote alarm.
- 3:** IO Dump active only in local alarm, inactive in external alarm.



## 2.0 PIN DESCRIPTIONS

**TABLE 2-1: PIN FUNCTION TABLE**

Pin	Symbol	DESCRIPTION
1	C1	The capacitor connected to this pin sets the photo amplifier gain (high) for the push-to-test and chamber sensitivity test. The size of this capacitor depends on the chamber background reflections. $A = 1 + (C1/10)$ , where C1 is in pF. The gain should be < 10000.
2	C2	The capacitor connected to this pin sets the photo amplifier gain (normal) during standby. The value of this capacitor depends on the smoke sensitivity required. $A = 1 + (C2/10)$ , where C2 is in pF.
3	DETECT	Positive input to the photo amplifier. This input is normally connected to the cathode of an external photo diode operated at zero bias.
4	STROBE	Regulated output voltage of $V_{DD} - 5$ , which is active during a test for smoke. This output is the negative side of the photo amplifier circuitry.
5	$V_{DD}$	Connect to the positive supply voltage
6	IREDD	Provides a regulated pulsed output voltage pre-driver for the infrared emitter. This output usually drives the base of an NPN transistor.
7	IO	This bidirectional pin provides the capability to interconnect many detectors in a single system. This pin has an internal pull-down device.
8	HB	This pin is connected to the metal electrode of a piezoelectric transducer.
9	HS	HS is a complementary output to HB and connects to the ceramic electrode of the piezoelectric transducer.
10	FEED	Usually connected to the feedback electrode through a current limiting resistor. When not used, this pin must be connected to either $V_{DD}$ or $V_{SS}$ .
11	LED	Open drain NMOS output used to drive a visible LED.
12	COSC	A capacitor connected to this pin with parallel resistor sets the internal clock low time, which is approximately the clock period.
13	ROSC	A resistor between this pin and pin 12 (COSC) sets the internal clock high time. This also sets the IREDD pulse width (100 - 200 $\mu$ s).
14	$V_{SS}$	Connect to the negative supply voltage.
15	LBSET	This input is connected to a $V_{DD}$ reference voltage to set the low battery warning voltage.
16	TEST	This input is used to invoke two test modes. This input has an internal pull-down.

## 3.0 CIRCUIT DESCRIPTION AND APPLICATION NOTES

**Note:** All timing references are nominal. See [Section 1.0 “Electrical Characteristics”](#) for limits.

### 3.1 Standby Internal Timing

With the external components specified in [Figure Typical Applications](#) for ROSC and COSC, the internal oscillator has a nominal period of 7.9 ms. Normally, the analog circuitry is powered down to minimize standby current (typically 4  $\mu$ A at 9V). Once every 8.1 seconds, the detection circuitry (normal gain) is powered up for 7.9 ms. Prior to the completion of the 7.9 ms period, the IRED pulse is active for 100  $\mu$ s. At the conclusion of the 7.9 ms period, the photo amplifier is compared to an internal reference to determine the chamber status and it is latched. If a smoke condition is present, the period to the next detection decreases and additional checks are made. Three consecutive smoke detections cause the device to go into alarm and the horn circuit and interconnect become active.

Once every 32 seconds, the status of the battery voltage is checked. This status is checked and latched at the conclusion of the LED pulse. In addition, once every 32 seconds the chamber test is activated and, using the high gain mode (capacitor C1), a check of the chamber is made by amplifying background reflections. If either the low battery or the photo chamber test fails, the horn chirps for 7.9 ms every 32 seconds.

The oscillator period is determined by the values of R9, R12 and C5 (see [Figure Typical Applications](#)). The oscillator period is  $T = TR + TF$ , where  $TR = 0.6931 \times R12 \times C5$  and  $TF = 0.6931 \times R9 \times C5$ .

### 3.2 Smoke Detection Circuitry

A comparator analyzes the photo amp output against an internal reference voltage. If the required number of consecutive smoke conditions is met, then the device goes into local alarm and the horn becomes active. In local alarm, the C2 gain is internally increased by ~10% to provide alarm hysteresis.

### 3.3 Push to Test Operation

If the TEST input pin is activated ( $V_{IH}$ ), then, after one internal clock cycle, the smoke detection rate increases to once every 250 ms. In this mode, the high gain capacitor C1 is selected and background reflections are used to simulate a smoke condition. After the required consecutive detections, the device goes into a local alarm condition. When the TEST input is deactivated ( $V_{IL}$ ) and after one clock cycle, the normal gain capacitor C1 is selected.

The detection rate continues at once every 250 ms until three consecutive no-smoke conditions are detected. At this point, the device returns to standby timing.

### 3.4 LED Operation

In standby, the LED is pulsed on for 7.9 ms every 32 seconds. In a local alarm condition or the push-to-test alarm, the LED pulse frequency is increased to once every 0.5s. In the case of a remote alarm, the LED does not activate.

### 3.5 Interconnect Operation

The bidirectional IO pin allows for interconnection of multiple detectors. In a local alarm condition, this pin is driven high immediately through a constant current source. Shorting this output to ground does not cause excessive current. The IO is ignored as an input during a local alarm.

The IO pin also has an NMOS discharge device that is active for 1s after the conclusion of any type of local alarm. This device helps to quickly discharge any capacitance associated with the interconnect line.

If a remote active high signal is detected, the device goes into remote alarm and the horn becomes active. Internal protection circuitry allows for the signaling unit to have a higher supply voltage than the signaled unit without excessive current draw.

The interconnect input has a 500 ms nominal digital filter. This allows for interconnection to other types of alarms (carbon monoxide for example) that can have a pulsed interconnect signal.

### 3.6 Low Battery and Chamber Test

While in standby, an internal reference is compared to the voltage divided  $V_{DD}$  supply. Low battery status is latched at the conclusion of the LED pulse. The horn chirps for 7.9 ms every 32s, until the low battery condition no longer exists. In standby, a chamber test is also performed every 32 seconds, by switching to the high-gain capacitor C1 and sensing the photo chamber background reflections. Two consecutive chamber test failures also cause the horn to chirp for 7.9 ms every 32 seconds. The low battery chirp occurs next to the LED pulse and the failed chamber test chirps 16.2 seconds later. The low battery and chamber tests are not performed in a local or remote alarm condition. The low battery alarm threshold is approximately equal to  $((5 \times R15)/R14) + 5$ , where R15 and R16 are in the same units.

### 3.7 Diagnostic Mode

In addition to the normal function of the TEST input, a special Diagnostic mode is available for the calibration and testing of the smoke detector. Taking the TEST pin below  $V_{SS}$  and sourcing  $\sim 240 \mu A$  out of the pin for one clock cycle enables the Diagnostic mode. In the Diagnostic mode, some of the pin functions are redefined (see Table 3-1). In addition in this mode, STROBE is always enabled and the IRED is pulsed at the clock rate of 7.9 ms nominal.

**TABLE 3-1: PIN FUNCTIONS IN DIAGNOSTIC MODE**

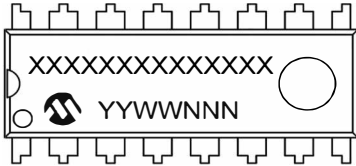
Pin	Symbol	Description
7	IO	Disabled as an output. A high on this pin directs the photo amplifier output to pin C1 (1) or C2 (2), determined by the level on LBSET (15). Amplification occurs during the IRED active time.
15	LBSET	If IO is high, then this pin controls the gain capacitor that is used. If LBSET is low, then normal gain is selected and the photo amplifier output appears on C1 (1). If LBSET is high, then high gain is selected and the photo amplifier output is on C2 (2).
10	FEED	If LBSET (15) is low, then taking this input high enables hysteresis, which is a nominal 10% gain increase in normal gain mode.
12	COSC	If desired, this pin can be driven by an external clock.
8	HORNB	This pin becomes the smoke integrator output. A high level indicates that an alarm condition has been detected.
11	LED	The LED pin is used as a low battery indicator. For $V_{DD}$ above the low battery threshold the open drain NMOS is off. If $V_{DD}$ falls below the threshold, the NMOS turns on.

# RE46C141

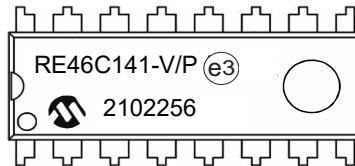
## 4.0 PACKAGING INFORMATION

### 4.1 Package Marking Information<sup>(1)</sup>

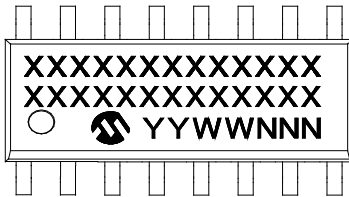
16-Lead PDIP (300 mil)



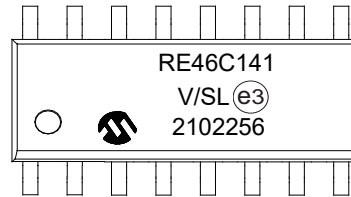
Example:



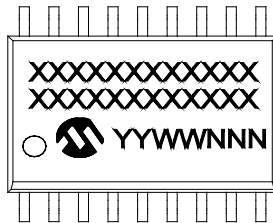
16-Lead Narrow SOIC (3.90 mm)



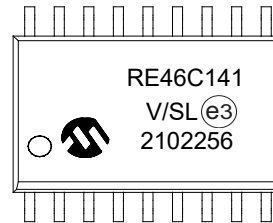
Example:



16-Lead Wide SOIC (7.50 mm)



Example:

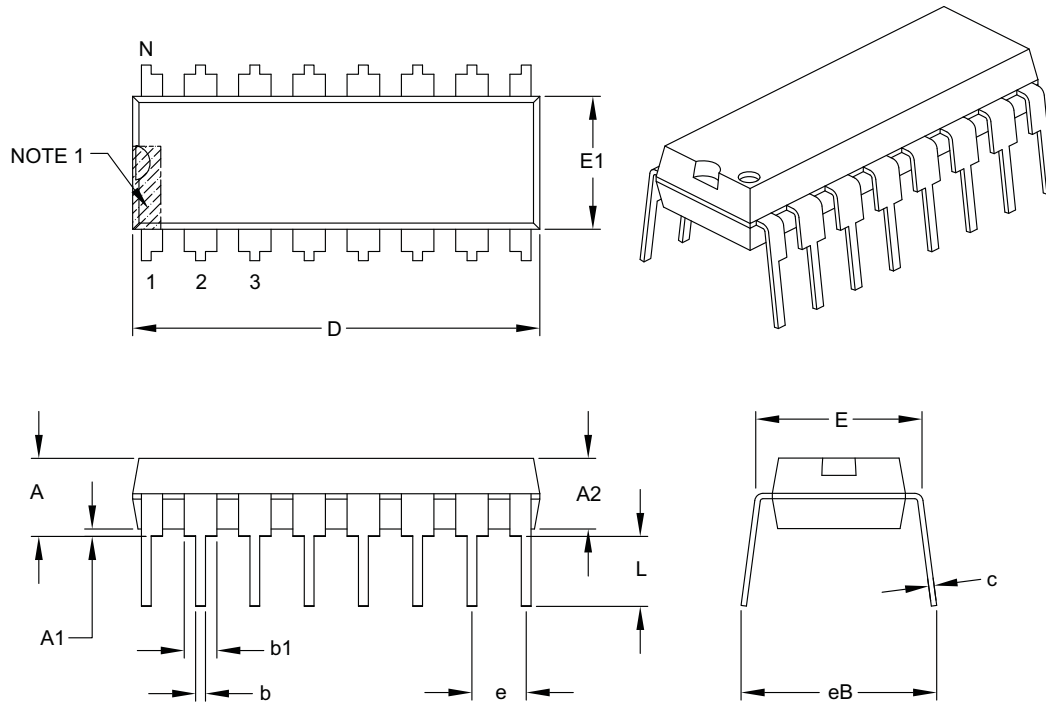


<b>Legend:</b>	XX...X	Customer-specific information
	Y	Year code (last digit of calendar year)
	YY	Year code (last 2 digits of calendar year)
	WW	Week code (week of January 1 is week '01')
	NNN	Alphanumeric traceability code
	(e3)	Pb-free JEDEC designator for Matte Tin (Sn)
	*	This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package.

**Note 1:** In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information.

## 16-Lead Plastic Dual In-Line (P) – 300 mil Body [PDIP]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



Dimension Limits		INCHES		
		MIN	NOM	MAX
Number of Pin	N	16		
Pitch	e	.100 BSC		
Top to Seating Plane	A	–	–	.210
Molded Package Thickness	A2	.115	.130	.195
Base to Seating Plane	A1	.015	–	–
Shoulder to Shoulder Width	E	.290	.310	.325
Molded Package Width	E1	.240	.250	.280
Overall Length	D	.735	.755	.775
Tip to Seating Plane	L	.115	.130	.150
Lead Thickness	c	.008	.010	.015
Upper Lead Width	b1	.045	.060	.070
Lower Lead Width	b	.014	.018	.022
Overall Row Spacing §	eB	–	–	.430

**Notes:**

1. Pin 1 visual index feature may vary, but must be located within the hatched area.
2. § Significant Characteristic.
3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" per side.
4. Dimensioning and tolerancing per ASME Y14.5M.

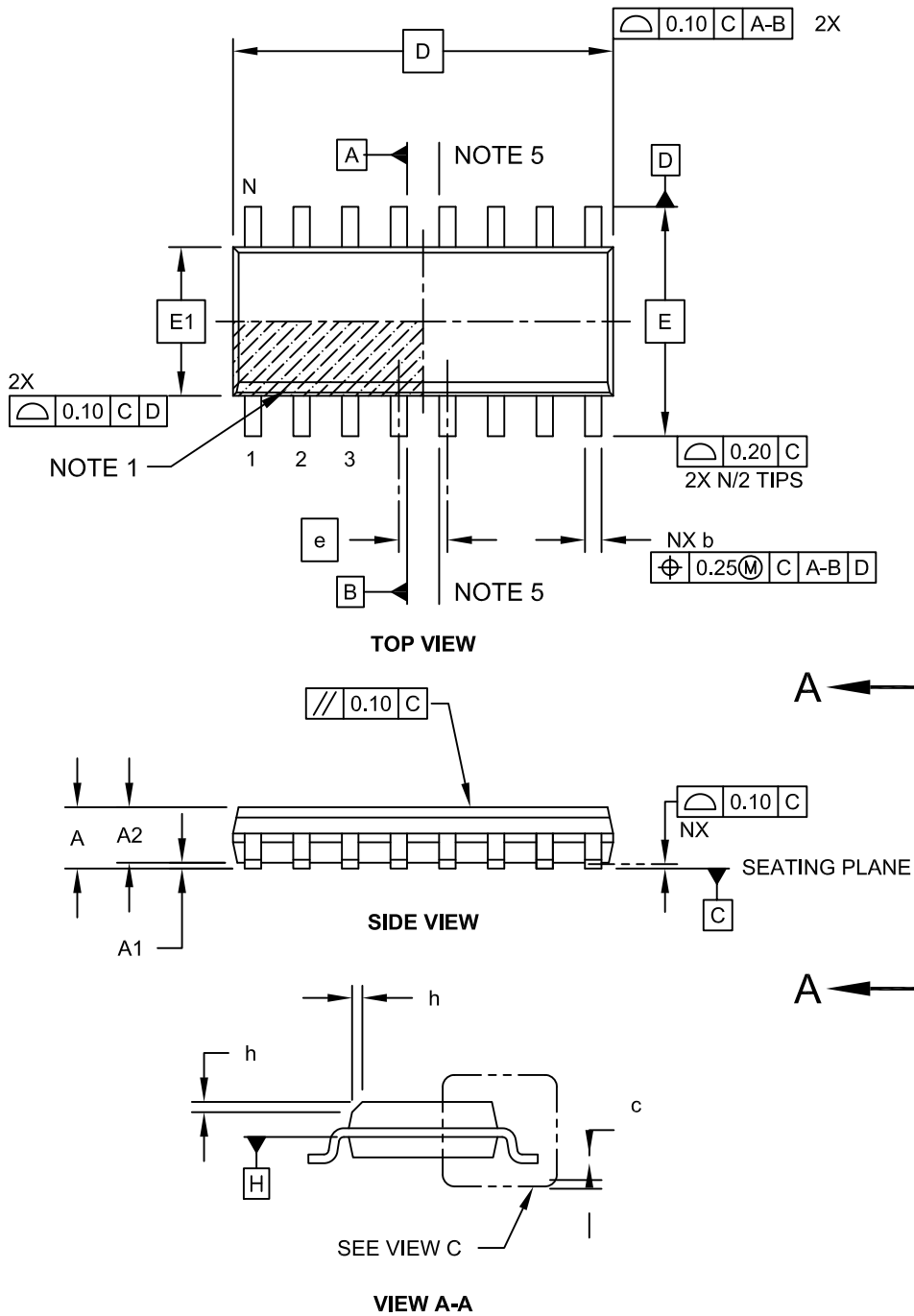
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-017B

# RE46C141

## 16-Lead Plastic Small Outline (SL) - Narrow, 3.90 mm Body [SOIC]

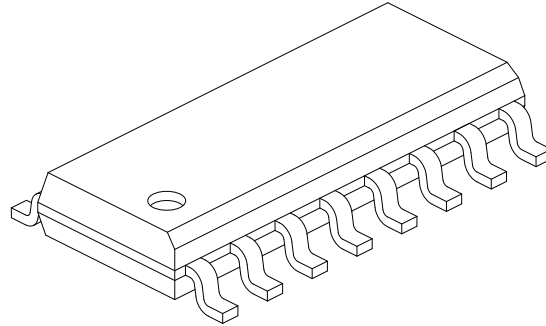
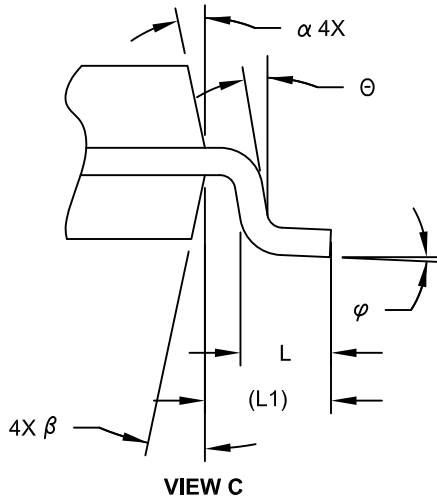
**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



Microchip Technology Drawing No. C04-108C Sheet 1 of 2

## 16-Lead Plastic Small Outline (SL) - Narrow, 3.90 mm Body [SOIC]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



Dimension Limits	Units	MILLIMETERS		
		MIN	NOM	MAX
Number of Pins	N	16		
Pitch	e	1.27 BSC		
Overall Height	A	-	-	1.75
Molded Package Thickness	A2	1.25	-	-
Standoff §	A1	0.10	-	0.25
Overall Width	E	6.00 BSC		
Molded Package Width	E1	3.90 BSC		
Overall Length	D	9.90 BSC		
Chamfer (Optional)	h	0.25	-	0.50
Foot Length	L	0.40	-	1.27
Footprint	L1	1.04 REF		
Lead Angle	$\theta$	0°	-	-
Foot Angle	$\phi$	0°	-	8°
Lead Thickness	c	0.10	-	0.25
Lead Width	b	0.31	-	0.51
Mold Draft Angle Top	$\alpha$	5°	-	15°
Mold Draft Angle Bottom	$\beta$	5°	-	15°

**Notes:**

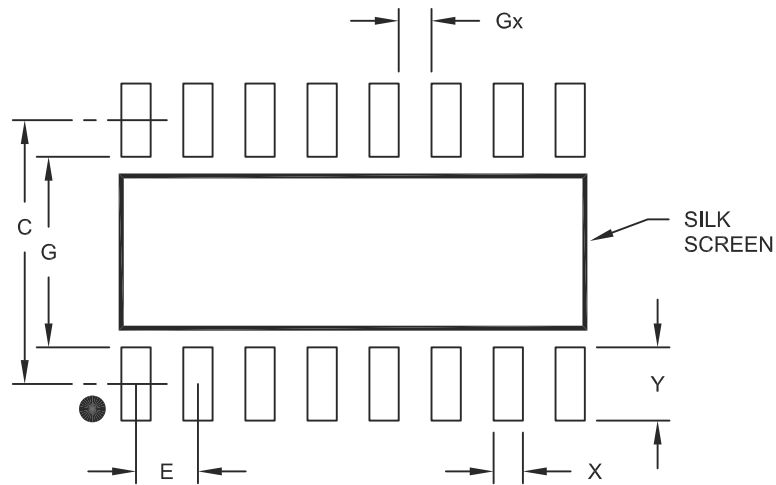
- Pin 1 visual index feature may vary, but must be located within the hatched area.
- § Significant Characteristic
- Dimension D does not include mold flash, protrusions or gate burrs, which shall not exceed 0.15 mm per end. Dimension E1 does not include interlead flash or protrusion, which shall not exceed 0.25 mm per side.
- Dimensioning and tolerancing per ASME Y14.5M  
 BSC: Basic Dimension. Theoretically exact value shown without tolerances.  
 REF: Reference Dimension, usually without tolerance, for information purposes only.
- Datums A & B to be determined at Datum H.

Microchip Technology Drawing No. C04-108C Sheet 2 of 2

# RE46C141

16-Lead Plastic Small Outline (SL) - Narrow, 3.90 mm Body [SOIC]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



## RECOMMENDED LAND PATTERN

		Units	MILLIMETERS		
		Dimension Limits	MIN	NOM	MAX
Contact Pitch	E		1.27 BSC		
Contact Pad Spacing	C			5.40	
Contact Pad Width	X				0.60
Contact Pad Length	Y				1.50
Distance Between Pads	Gx		0.67		
Distance Between Pads	G		3.90		

**Notes:**

1. Dimensioning and tolerancing per ASME Y14.5M

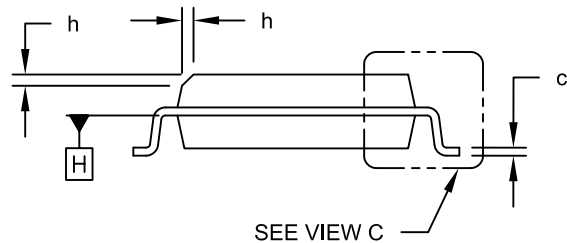
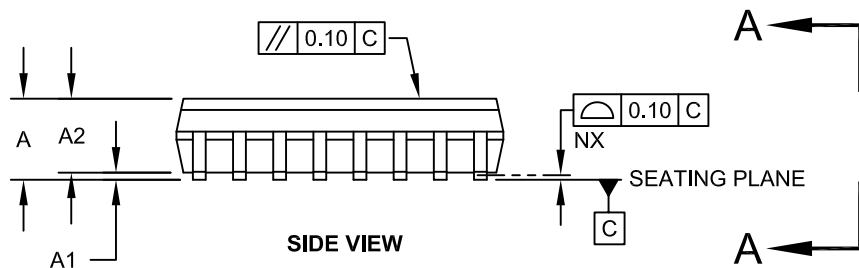
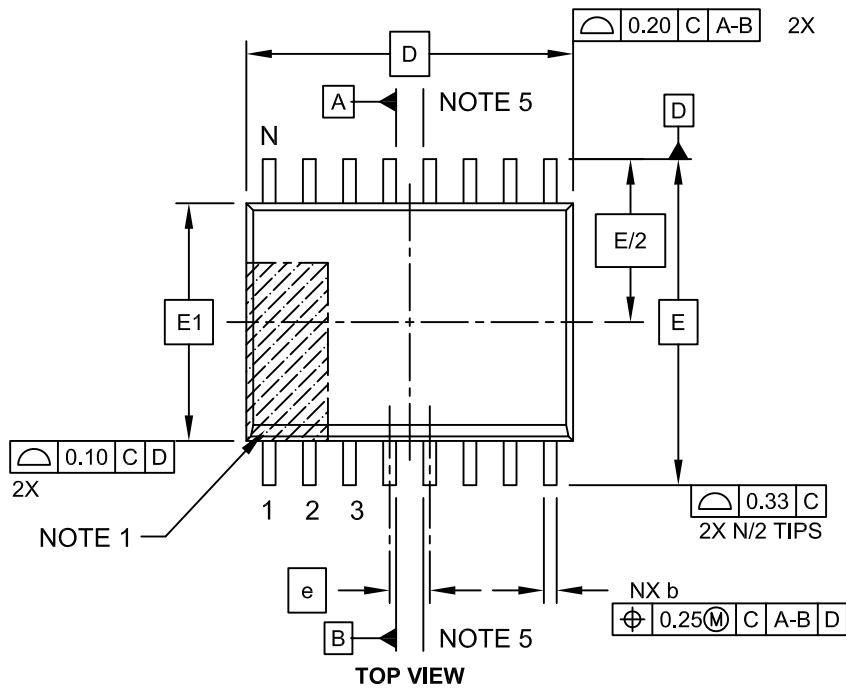
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2108A



## 16-Lead Plastic Small Outline (OE) - Wide, 7.50 mm Body [SOIC]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>

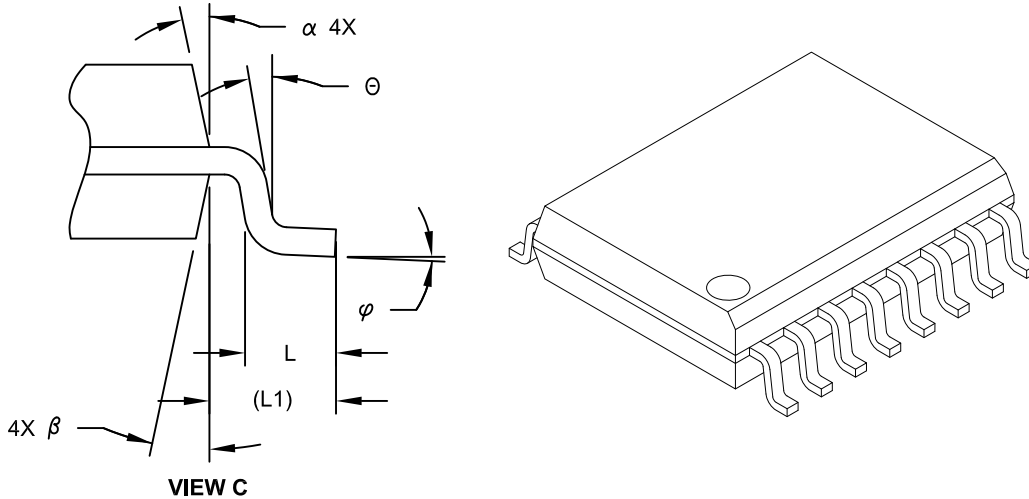


Microchip Technology Drawing C04-102C Sheet 1 of 2

# RE46C141

## 16-Lead Plastic Small Outline (OE) - Wide, 7.50 mm Body [SOIC]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



Dimension Limits	Units	MILLIMETERS		
		MIN	NOM	MAX
Number of Pins	N	16		
Pitch	e	1.27 BSC		
Overall Height	A	-	-	2.65
Molded Package Thickness	A2	2.05	-	-
Standoff §	A1	0.10	-	0.30
Overall Width	E	10.30 BSC		
Molded Package Width	E1	7.50 BSC		
Overall Length	D	10.30 BSC		
Chamfer (Optional)	h	0.25	-	0.75
Foot Length	L	0.40	-	1.27
Footprint	L1	1.40 REF		
Lead Angle	θ	0°	-	-
Foot Angle	φ	0°	-	8°
Lead Thickness	c	0.20	-	0.33
Lead Width	b	0.31	-	0.51
Mold Draft Angle Top	α	5°	-	15°
Mold Draft Angle Bottom	β	5°	-	15°

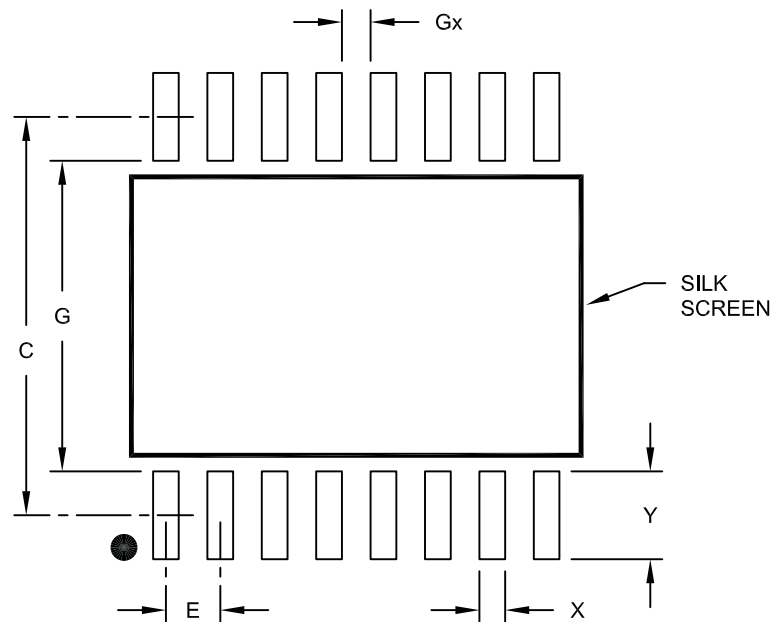
**Notes:**

- Pin 1 visual index feature may vary, but must be located within the hatched area.
- § Significant Characteristic
- Dimension D does not include mold flash, protrusions or gate burrs, which shall not exceed 0.15 mm per end. Dimension E1 does not include interlead flash or protrusion, which shall not exceed 0.25 mm per side.
- Dimensioning and tolerancing per ASME Y14.5M  
 BSC: Basic Dimension. Theoretically exact value shown without tolerances.  
 REF: Reference Dimension, usually without tolerance, for information purposes only.
- Datums A & B to be determined at Datum H.

Microchip Technology Drawing No. C04-102C Sheet 2 of 2

## 16-Lead Plastic Small Outline (OE) – Wide, 7.50 mm Body [SOIC] Land Pattern

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



RECOMMENDED LAND PATTERN

		Units	MILLIMETERS		
		Dimension Limits	MIN	NOM	MAX
Contact Pitch	E		1.27 BSC		
Contact Pad Spacing	C			9.30	
Contact Pad Width	X				0.60
Contact Pad Length	Y				2.05
Distance Between Pads	Gx		0.67		
Distance Between Pads	G		7.25		

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2102A

# RE46C141

---

NOTES:

## APPENDIX A: REVISION HISTORY

### Revision C (June 2021)

- Updated document to latest Microchip formatting.
- Added [Section 4.0 “Packaging Information”](#).
- Updated [Table AC Electrical Characteristics](#).

### Revision B (2009)

- Replaced RE46C141 from R&E International.

### Revision A

- Initial release of this document.

NOTES:

## PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

<u>PART NO.</u>	X	XX	[X] <sup>(1)</sup>	F
Device	Package	Number of Pins	Tape and Reel Option	Lead-Free
<b>Device:</b>	RE46C141			
<b>Package:</b>	S	=	SOIC	
	SW	=	SOIC (Wide)	
	E	=	PDIP	
<b>Tape and Reel Option:</b>	Blank	=	Standard packaging (tube or tray)	
	T	=	Tape and Reel <sup>(1)</sup>	
<b>Lead-Free:</b>	F	=	Lead-Free	

**Examples:**

- a) RE46C141E16F = 16LD PDIP, Standard Packaging, Lead-Free.
- b) RE46C141S16F = 16LD SOIC, Standard Packaging, Lead-Free
- c) RE46C141SW16F = 16LD SOIC (Wide), Standard Packaging, Lead-Free
- d) RE46C141S16TF = 16LD SOIC, Tape and Reel, Lead-Free
- e) RE46C141SW16TF = 16LD SOIC (Wide), Tape and Reel, Lead-Free

**Note 1:** Tape and Reel identifier only appears in the catalog part number description. This identifier is used for ordering purposes and is not printed on the device package. Check with your Microchip Sales Office for package availability with the Tape and Reel option.

# RE46C141

---

NOTES:



---

**Note the following details of the code protection feature on Microchip devices:**

- Microchip products meet the specifications contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is secure when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods being used in attempts to breach the code protection features of the Microchip devices. We believe that these methods require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data Sheets. Attempts to breach these code protection features, most likely, cannot be accomplished without violating Microchip's intellectual property rights.
- Microchip is willing to work with any customer who is concerned about the integrity of its code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of its code. Code protection does not mean that we are guaranteeing the product is "unbreakable". Code protection is constantly evolving. We at Microchip are committed to continuously improving the code protection features of our products. Attempts to break Microchip's code protection feature may be a violation of the Digital Millennium Copyright Act. If such acts allow unauthorized access to your software or other copyrighted work, you may have a right to sue for relief under that Act.

---

Information contained in this publication is provided for the sole purpose of designing with and using Microchip products. Information regarding device applications and the like is provided only for your convenience and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications.

THIS INFORMATION IS PROVIDED BY MICROCHIP "AS IS". MICROCHIP MAKES NO REPRESENTATIONS OR WARRANTIES OF ANY KIND WHETHER EXPRESS OR IMPLIED, WRITTEN OR ORAL, STATUTORY OR OTHERWISE, RELATED TO THE INFORMATION INCLUDING BUT NOT LIMITED TO ANY IMPLIED WARRANTIES OF NON-INFRINGEMENT, MERCHANTABILITY, AND FITNESS FOR A PARTICULAR PURPOSE OR WARRANTIES RELATED TO ITS CONDITION, QUALITY, OR PERFORMANCE.

IN NO EVENT WILL MICROCHIP BE LIABLE FOR ANY INDIRECT, SPECIAL, PUNITIVE, INCIDENTAL OR CONSEQUENTIAL LOSS, DAMAGE, COST OR EXPENSE OF ANY KIND WHATSOEVER RELATED TO THE INFORMATION OR ITS USE, HOWEVER CAUSED, EVEN IF MICROCHIP HAS BEEN ADVISED OF THE POSSIBILITY OR THE DAMAGES ARE FORESEEABLE. TO THE FULLEST EXTENT ALLOWED BY LAW, MICROCHIP'S TOTAL LIABILITY ON ALL CLAIMS IN ANY WAY RELATED TO THE INFORMATION OR ITS USE WILL NOT EXCEED THE AMOUNT OF FEES, IF ANY, THAT YOU HAVE PAID DIRECTLY TO MICROCHIP FOR THE INFORMATION. Use of Microchip devices in life support and/or safety applications is entirely at the buyer's risk, and the buyer agrees to defend, indemnify and hold harmless Microchip from any and all damages, claims, suits, or expenses resulting from such use. No licenses are conveyed, implicitly or otherwise, under any Microchip intellectual property rights unless otherwise stated.

**Trademarks**

The Microchip name and logo, the Microchip logo, Adaptec, AnyRate, AVR, AVR logo, AVR Freaks, BesTime, BitCloud, chipKIT, chipKIT logo, CryptoMemory, CryptoRF, dsPIC, FlashFlex, flexPWR, HELDO, IGL00, JukeBlox, KeeLoq, Kleer, LANCheck, LinkMD, maXStylus, maXTouch, MediaLB, megaAVR, Microsemi, Microsemi logo, MOST, MOST logo, MPLAB, OptoLyzer, PackeTime, PIC, picoPower, PICSTART, PIC32 logo, PolarFire, Prochip Designer, QTouch, SAM-BA, SenGenuity, SpyNIC, SST, SST Logo, SuperFlash, Symmetricom, SyncServer, Tachyon, TimeSource, tinyAVR, UNI/O, Vectron, and XMEGA are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

AgileSwitch, APT, ClockWorks, The Embedded Control Solutions Company, EtherSynch, FlashTec, Hyper Speed Control, HyperLight Load, IntelliMOS, Libero, motorBench, mTouch, Powermite 3, Precision Edge, ProASIC, ProASIC Plus, ProASIC Plus logo, Quiet-Wire, SmartFusion, SyncWorld, Temux, TimeCesium, TimeHub, TimePictra, TimeProvider, WinPath, and ZL are registered trademarks of Microchip Technology Incorporated in the U.S.A.

Adjacent Key Suppression, AKS, Analog-for-the-Digital Age, Any Capacitor, AnyIn, AnyOut, Augmented Switching, BlueSky, BodyCom, CodeGuard, CryptoAuthentication, CryptoAutomotive, CryptoCompanion, CryptoController, dsPICDEM, dsPICDEM.net, Dynamic Average Matching, DAM, ECAN, Espresso T1S, EtherGREEN, IdealBridge, In-Circuit Serial Programming, ICSP, INICnet, Intelligent Paralleling, Inter-Chip Connectivity, JitterBlocker, maxCrypto, maxView, memBrain, Mindi, MiWi, MPASM, MPF, MPLAB Certified logo, MPLIB, MPLINK, MultiTRAK, NetDetach, Omniscient Code Generation, PICDEM, PICDEM.net, PICkit, PICtail, PowerSmart, PureSilicon, QMatrix, REAL ICE, Ripple Blocker, RTAX, RTG4, SAM-ICE, Serial Quad I/O, simpleMAP, SimpliPHY, SmartBuffer, SMART-I.S., storClad, SQI, SuperSwitcher, SuperSwitcher II, Switchtec, SynchroPHY, Total Endurance, TSHARC, USBCheck, VariSense, VectorBlox, VeriPHY, ViewSpan, WiperLock, XpressConnect, and ZENA are trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

SQTP is a service mark of Microchip Technology Incorporated in the U.S.A.

The Adaptec logo, Frequency on Demand, Silicon Storage Technology, and Symmcom are registered trademarks of Microchip Technology Inc. in other countries.

GestIC is a registered trademark of Microchip Technology Germany II GmbH & Co. KG, a subsidiary of Microchip Technology Inc., in other countries.

All other trademarks mentioned herein are property of their respective companies.

© 2009-2021, Microchip Technology Incorporated, All Rights Reserved.

ISBN: 978-1-5224-8363-2

For information regarding Microchip's Quality Management Systems, please visit [www.microchip.com/quality](http://www.microchip.com/quality).



# MICROCHIP

## Worldwide Sales and Service

### AMERICAS

**Corporate Office**  
2355 West Chandler Blvd.  
Chandler, AZ 85224-6199  
Tel: 480-792-7200  
Fax: 480-792-7277  
Technical Support:  
<http://www.microchip.com/support>  
Web Address:  
[www.microchip.com](http://www.microchip.com)

#### Atlanta

Duluth, GA  
Tel: 678-957-9614  
Fax: 678-957-1455

#### Austin, TX

Tel: 512-257-3370

#### Boston

Westborough, MA  
Tel: 774-760-0087  
Fax: 774-760-0088

#### Chicago

Itasca, IL  
Tel: 630-285-0071  
Fax: 630-285-0075

#### Dallas

Addison, TX  
Tel: 972-818-7423  
Fax: 972-818-2924

#### Detroit

Novi, MI  
Tel: 248-848-4000

#### Houston, TX

Tel: 281-894-5983

#### Indianapolis

Noblesville, IN  
Tel: 317-773-8323  
Fax: 317-773-5453  
Tel: 317-536-2380

#### Los Angeles

Mission Viejo, CA  
Tel: 949-462-9523  
Fax: 949-462-9608  
Tel: 951-273-7800

#### Raleigh, NC

Tel: 919-844-7510

#### New York, NY

Tel: 631-435-6000

#### San Jose, CA

Tel: 408-735-9110  
Tel: 408-436-4270

#### Canada - Toronto

Tel: 905-695-1980  
Fax: 905-695-2078

### ASIA/PACIFIC

**Australia - Sydney**  
Tel: 61-2-9868-6733

**China - Beijing**  
Tel: 86-10-8569-7000

**China - Chengdu**  
Tel: 86-28-8665-5511

**China - Chongqing**  
Tel: 86-23-8980-9588

**China - Dongguan**  
Tel: 86-769-8702-9880

**China - Guangzhou**  
Tel: 86-20-8755-8029

**China - Hangzhou**  
Tel: 86-571-8792-8115

**China - Hong Kong SAR**  
Tel: 852-2943-5100

**China - Nanjing**  
Tel: 86-25-8473-2460

**China - Qingdao**  
Tel: 86-532-8502-7355

**China - Shanghai**  
Tel: 86-21-3326-8000

**China - Shenyang**  
Tel: 86-24-2334-2829

**China - Shenzhen**  
Tel: 86-755-8864-2200

**China - Suzhou**  
Tel: 86-186-6233-1526

**China - Wuhan**  
Tel: 86-27-5980-5300

**China - Xian**  
Tel: 86-29-8833-7252

**China - Xiamen**  
Tel: 86-592-2388138

**China - Zhuhai**  
Tel: 86-756-3210040

### ASIA/PACIFIC

**India - Bangalore**  
Tel: 91-80-3090-4444

**India - New Delhi**  
Tel: 91-11-4160-8631

**India - Pune**  
Tel: 91-20-4121-0141

**Japan - Osaka**  
Tel: 81-6-6152-7160

**Japan - Tokyo**  
Tel: 81-3-6880-3770

**Korea - Daegu**  
Tel: 82-53-744-4301

**Korea - Seoul**  
Tel: 82-2-554-7200

**Malaysia - Kuala Lumpur**  
Tel: 60-3-7651-7906

**Malaysia - Penang**  
Tel: 60-4-227-8870

**Philippines - Manila**  
Tel: 63-2-634-9065

**Singapore**  
Tel: 65-6334-8870

**Taiwan - Hsin Chu**  
Tel: 886-3-577-8366

**Taiwan - Kaohsiung**  
Tel: 886-7-213-7830

**Taiwan - Taipei**  
Tel: 886-2-2508-8600

**Thailand - Bangkok**  
Tel: 66-2-694-1351

**Vietnam - Ho Chi Minh**  
Tel: 84-28-5448-2100

### EUROPE

**Austria - Wels**  
Tel: 43-7242-2244-39  
Fax: 43-7242-2244-393

**Denmark - Copenhagen**  
Tel: 45-4485-5910  
Fax: 45-4485-2829

**Finland - Espoo**  
Tel: 358-9-4520-820

**France - Paris**  
Tel: 33-1-69-53-63-20  
Fax: 33-1-69-30-90-79

**Germany - Garching**  
Tel: 49-8931-9700

**Germany - Haan**  
Tel: 49-2129-3766400

**Germany - Heilbronn**  
Tel: 49-7131-72400

**Germany - Karlsruhe**  
Tel: 49-721-625370

**Germany - Munich**  
Tel: 49-89-627-144-0  
Fax: 49-89-627-144-44

**Germany - Rosenheim**  
Tel: 49-8031-354-560

**Israel - Ra'anana**  
Tel: 972-9-744-7705

**Italy - Milan**  
Tel: 39-0331-742611  
Fax: 39-0331-466781

**Italy - Padova**  
Tel: 39-049-7625286

**Netherlands - Drunen**  
Tel: 31-416-690399  
Fax: 31-416-690340

**Norway - Trondheim**  
Tel: 47-7288-4388

**Poland - Warsaw**  
Tel: 48-22-3325737

**Romania - Bucharest**  
Tel: 40-21-407-87-50

**Spain - Madrid**  
Tel: 34-91-708-08-90  
Fax: 34-91-708-08-91

**Sweden - Gothenberg**  
Tel: 46-31-704-60-40

**Sweden - Stockholm**  
Tel: 46-8-5090-4654

**UK - Wokingham**  
Tel: 44-118-921-5800  
Fax: 44-118-921-5820